

Super-Junction Power Mosfet

1. Product Information

Features

- Low FOM $R_{DS(ON)} \times Q_G$
- Fast switching capability
- Lead free product is acquired

Applications

- Power supply
- Charger
- Solar/UPS-Micro inverter system

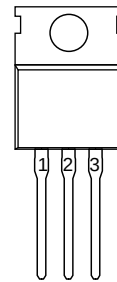
Quick reference

- $V_{DS} \geq 650 \text{ V}$
- $I_D \leq 25 \text{ A}$
- $R_{DS(ON)} \leq 140 \text{ m}\Omega @ V_{GS} = 10 \text{ V}$ (Type 110 m Ω)

Pin Description

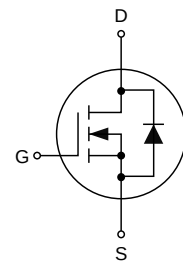
Pin	Description
1	Gate(G)
2	Drain(D)
3	Source(S)

Simplified Outline



Top View
TO-220

Symbol



Package Marking and Ordering Information

Part number	Marking	Package	Packaging	Quantity	Reel size	Tape width
KJCF65R140C	KJCF65R140C	TO-220	☐ Tape & Reel	N/A	N/A	N/A
			☒ Tube	1000 PCS	N/A	N/A

2. Absolute Maximum Ratings ($T_C=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Values	Unit
V_{DS}	Drain-Source Voltage	650	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Continuous Drain Current ($T_C=25^\circ\text{C}$)	25	A
	Continuous Drain Current ($T_C=100^\circ\text{C}$)	15.8	A
I_{DM}	Pulsed Drain Current	75	A
E_{AS}	Single Pulsed Avalanche Energy (L=30 mH)	120	mJ
dv/dt	Peak Diode Recovery dv/dt	50	V/ns
I_S	Continuous diode forward current	25	A
P_D	Power Dissipation	198	W
T_J, T_{stg}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction-Ambient	72	$^\circ\text{C/W}$
$R_{\theta JC}$	Thermal Resistance, Junction-Case	0.63	$^\circ\text{C/W}$

3. Electrical Characteristics (T_J=25°C, unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Type	Max	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0 V, I _D =250 μA	650	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =650 V, V _{GS} =0 V	-	-	5	μA
		V _{DS} =650 V, T _C =150°C	-	225	-	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±30 V, V _{DS} =0 V	-	-	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250 μA	3.0	-	4.5	V
R _{DS(ON)}	Drain-Source On-State Resistance	V _{GS} =10 V, I _D =12 A	-	110	140	mΩ
Dynamic Characteristics						
C _{iss}	Input Capacitance	V _{DS} =100 V, V _{GS} =0 V, f=1 MHz	-	1600	-	pF
C _{oss}	Output Capacitance		-	93	-	pF
C _{rss}	Reverse Transfer Capacitance		-	1.8	-	pF
Switching Characteristics						
t _{d(on)}	Turn-on Delay Time	V _{DS} =400 V, I _D =12 A, R _G =27 Ω, V _{GS} =10 V	-	63	-	ns
t _r	Turn-on Rise Time		-	60	-	ns
t _{d(off)}	Turn-off Delay Time		-	148	-	ns
t _f	Turn-off Fall Time		-	32	-	ns
R _{g,int}	Gate resistance	f=1 MHz	-	10	-	Ω
Q _g	Total Gate Charge	V _{DS} =520 V, I _D =12 A, V _{GS} =10 V	-	45	-	nC
Q _{gs}	Gate-Source Charge		-	13	-	nC
Q _{gd}	Gate-Drain Charge		-	23	-	nC
Source-Drain Diode Characteristics						
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} =0 V, I _F =12 A	-	0.85	1.15	V
Q _{rr}	Reverse Recovery Time	V _R =400 V, I _F =12 A, di/dt=100 A/μs	-	0.65	-	μC
T _{rr}	Reverse Recovery Charge		-	182	-	ns

4. Electrical Characteristics

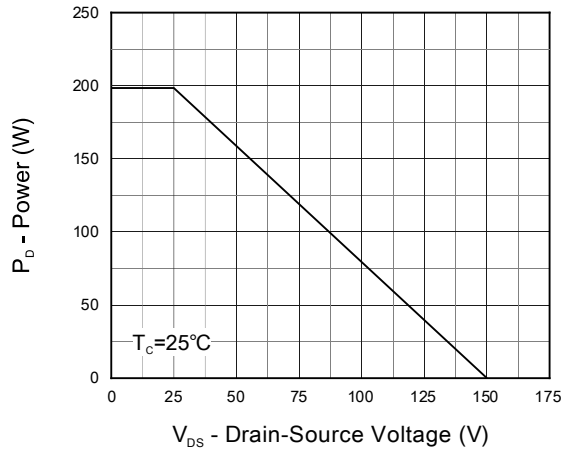


Fig 1. Power Capability

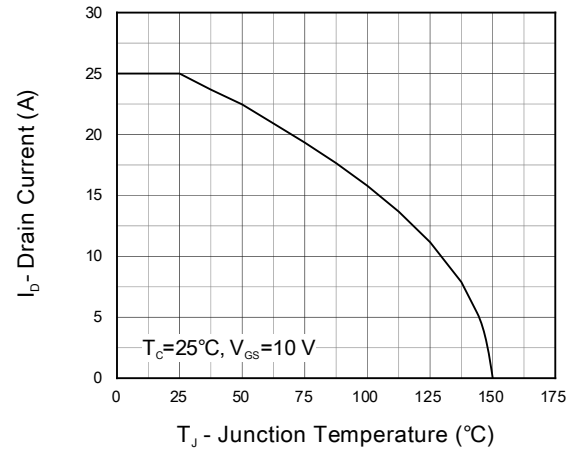


Fig 2. Current Capability

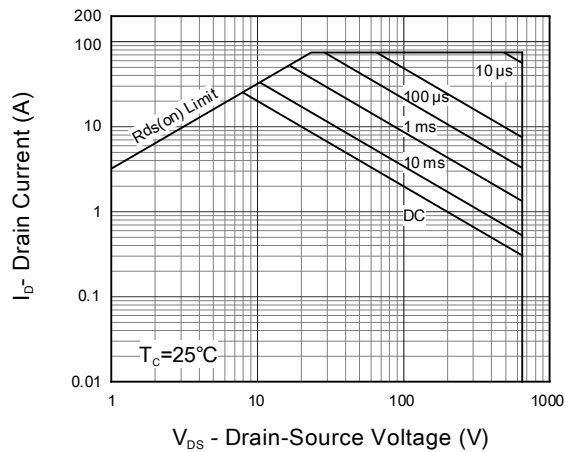


Fig 3. Safe Operation Area

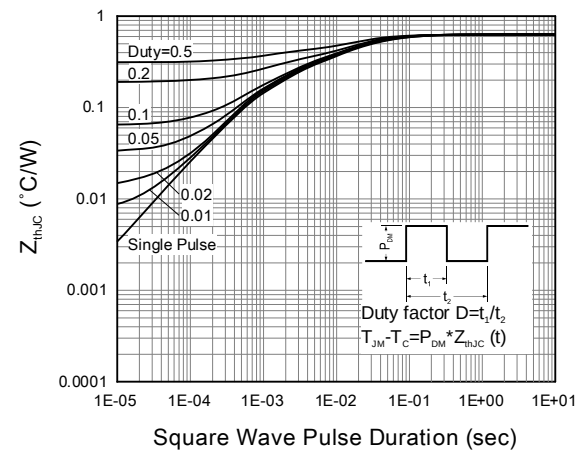


Fig 4. Transient Thermal Impedance

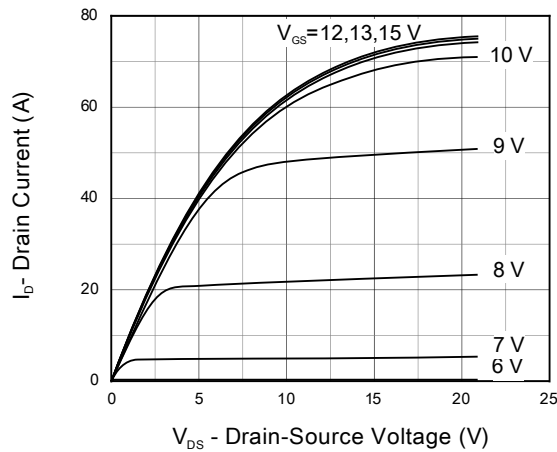


Fig 5. Output Characteristics
 $T_J=25^\circ\text{C}$

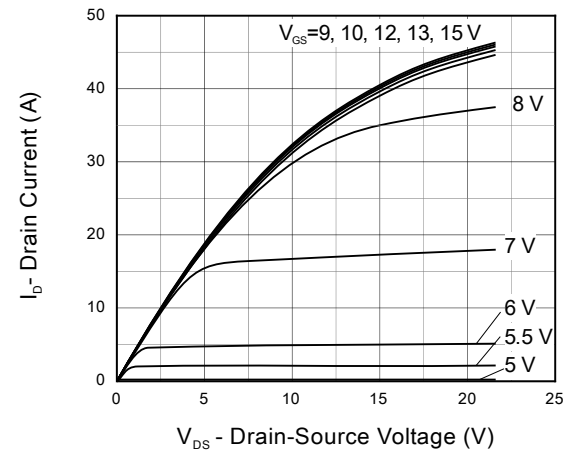


Fig 6. Output Characteristics
 $T_J=150^\circ\text{C}$

5. Electrical Characteristics (cont.)

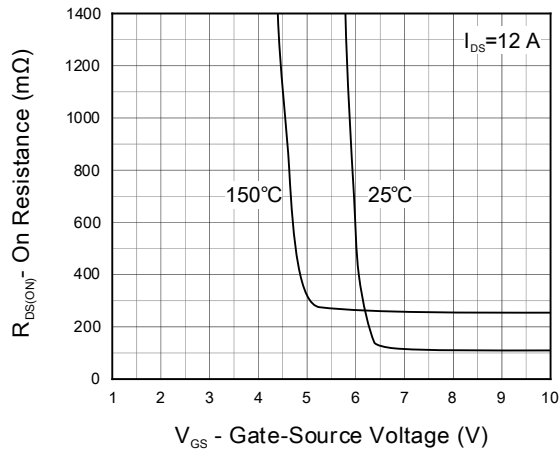


Fig 7. $R_{DS(ON)}$ vs. Gate Voltage

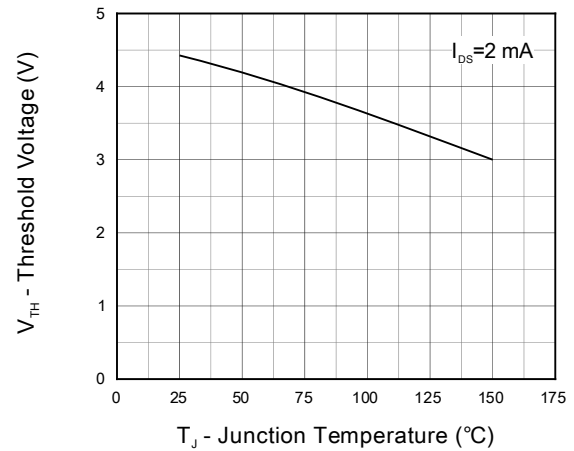


Fig 8. V_{TH} vs. Junction Temperature

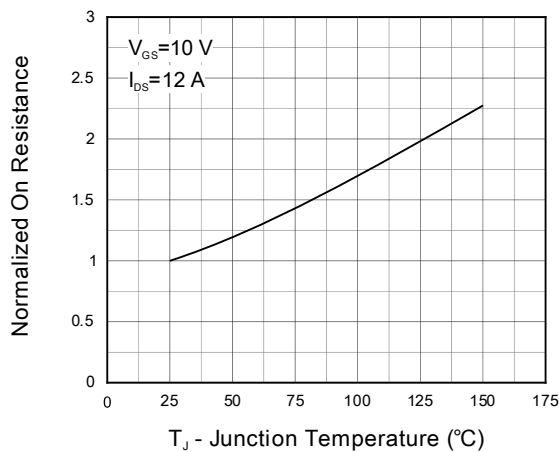


Fig 9. Normalized On Resistance

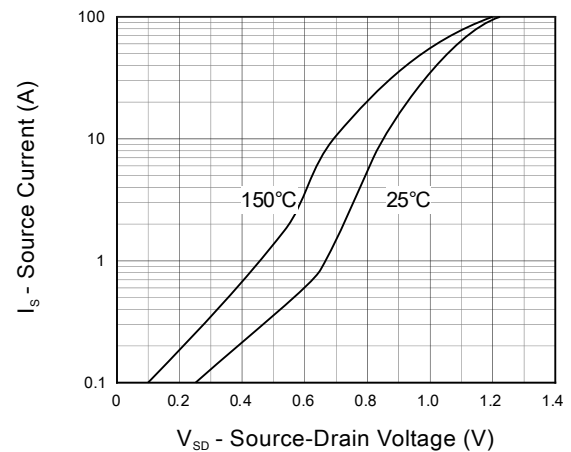


Fig 10. Diode Forward Current

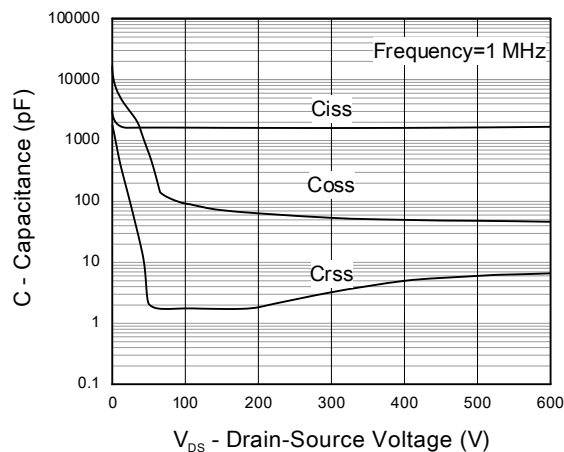


Fig 11. Capacitance

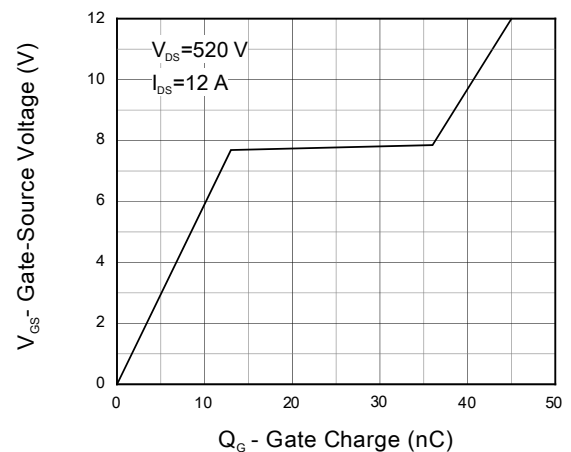
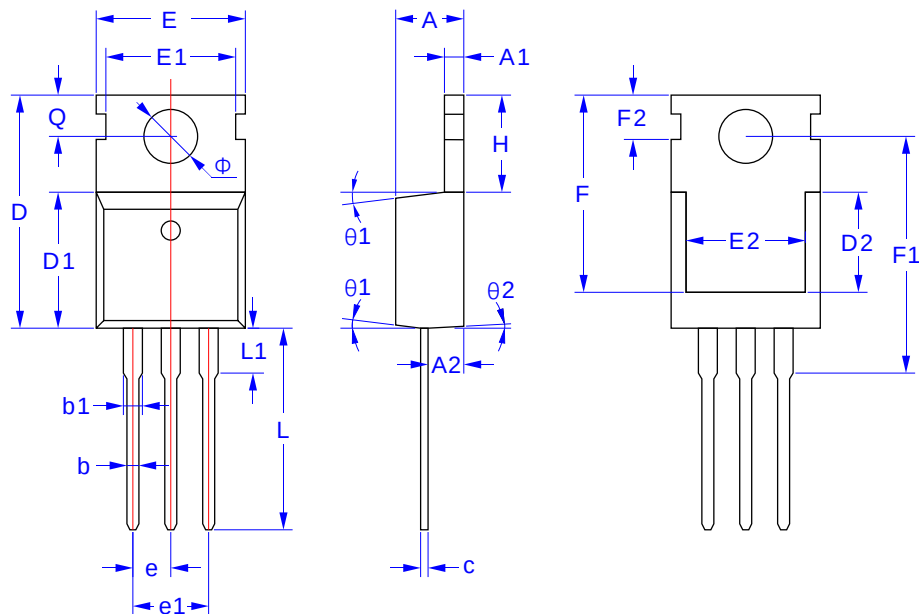


Fig 12. Gate Charge

5. Package Mechanical Data

TO-220 Package



Symbol	Dimensions in Millimeters		
	MIN	NOM	MAX
A	4.27	4.57	4.87
A1	1.15	1.30	1.45
A2	2.10	2.40	2.70
b	0.70	0.80	1.00
b1	1.17	1.27	1.50
c	0.40	0.50	0.65
D	15.50	15.80	16.10
D1	8.80	9.10	9.40
D2	5.70	6.70	7.00
E	9.70	10.00	10.30
E1	-	8.70	-
E2	7.00	8.00	8.40
e	2.54		
e1	5.08		
F	13.30	13.50	13.70
F1	15.50	15.90	16.30
F2	2.80	3.00	3.20
H	6.00	6.50	6.85
L	12.75	13.50	13.90
L1	-	3.10	3.40
Q	2.60	2.80	3.00
Φ	3.45	3.60	3.75
θ1	4°	7°	10°
θ2	0°	3°	6°